

S3AB thru S3MB

SURFACE MOUNT GLASS PASSIVATED RECTIFIERS

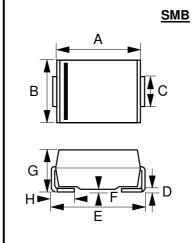
REVERSE VOLTAGE – 50 to 1000 Volts FORWARD CURRENT – 3.0 Amperes

FEATURES

- · Glass passivated chip
- · For surface mounted applications
- Low reverse leakage current
- · Low forward voltage drop
- · High current capability

MECHANICAL DATA

- · Case: Molded plastic
- Case Material molding compound, UL flammability classification 94V-0, (No Br. Sb. Cl.) "Halogen-free".
- Polarity: Color band denotes cathode
- Weight: 0.102 grams (Approximated)



SMB							
DIM.	MIN.	MAX					
Α	4.06	4.57					
В	3.30	3.94					
С	1.96	2.21					
D	0.15	0.31					
Е	5.21	5.59					
F	0.05	0.20					
G	2.01	2.50					
Н	0.76	1.52					
All dimension in millimeter							

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

ABSOLUTE RATINGS

PARAMETER	SYMBOL	S3AB	S3BB	S3DB	S3GB	S3JB	S3KB	S3MB	UNIT
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum DC blocking voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum average forward rectified current @ T _L =75°C	I _(AV)				3.0				Α
Peak forward surge current 8.3ms single half @T_=25°C sine-wave superimposed on rated load @T_=125°C	I _{FSM}				120 100				Α
Peak forward surge current 1ms single half @T_=25°C sine-wave superimposed on rated load @T_=125°C	I _{FSM}				240 200				Α
I ² t rating for fusing (t = 8.3ms)	l²t				42				A ² S
Typical junction capacitance (Note1)	C _J				40				pF
Operation and storage temperature range	T_J , T_{STG}	-55 to +150					°C		

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST C	ONDITIONS	SYMBOL	MAX.	UNIT
Forward voltage	I _F = 3.0A	T _J =25°C	V _F	1.15	V
Leakage current	V _R rated	TJ=25°C TJ=125°C	I _R	10 250	uA

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	TYP.	UNIT
	RthJ _A	55	
Typical thermal resistance (Note2)	RthJ∟	12	°C/W
	RthJc	12	

DYNAMIC ELECTRICAL CHARACTERISTICS

PARAMETER	TEST CONDITIONS	SYMBOL	TYP.		
Reverse recovery time	IF= 0.5A, Irr= 0.25A, IR =1.0A	T_RR	2000		
Note:	REV. 10, Dec2016, KS	DB03			

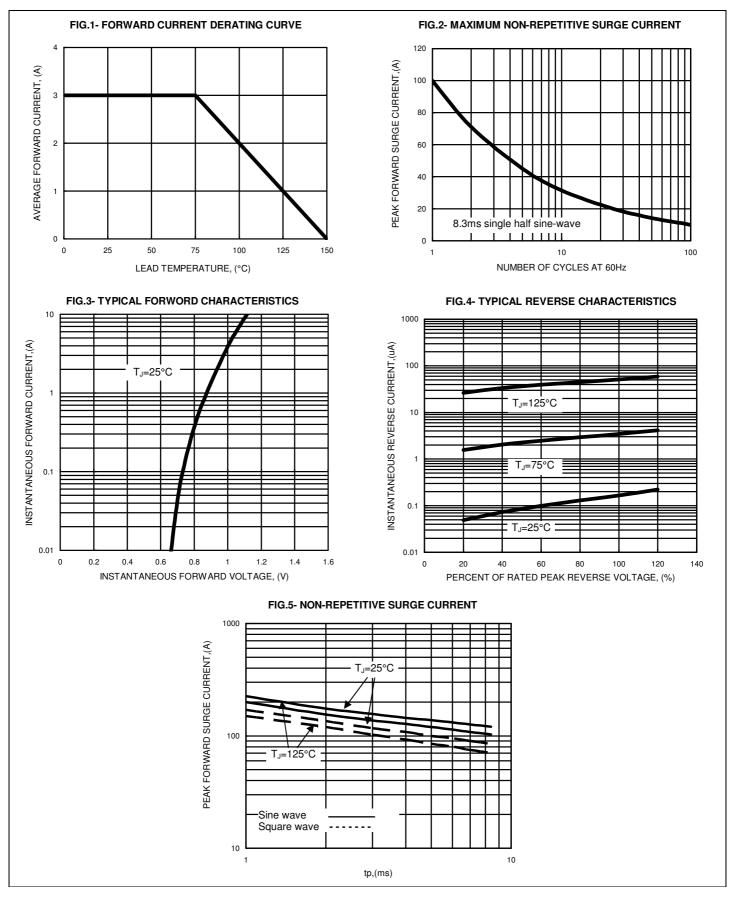
(1) Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

(2) Thermal resistance junction to ambient, lead and case.

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RATING AND CHARACTERISTIC CURVES S3AB thru S3MB







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